

October 2001

Six-Channel Discrete-to-Digital Interface Sensing Open / Ground Signals

DESCRIPTION

The HI-8420 is a six channel discrete-to-digital interface device. Mixed-signal CMOS technology is used to provide superior low-power performance. The HI-8420 has six separate Open / Ground sensing inputs. The device outputs are CMOS / TTL compatible and may be disabled (tri-state) using the $\overline{\text{CE}}$ and $\overline{\text{OE}}$ pins.

The device is a drop-in replacement for the DEI1026. For added functionality, the Holt HI-8422 offers eight channels of Open / Ground sensing and eight channels of 28V/Ground sensing in a single device.

The HI-8420 is offered in a small footprint 16-pin plastic package. Please contact the Holt sales department for other packaging options.

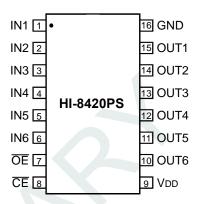
FEATURES

- Six independent Open / Ground sensing channels
- 5.0V single supply operation
- Low power CMOS technology
- Military processing options available
- Drop in replacement for DEI1026

FUNCTION TABLE

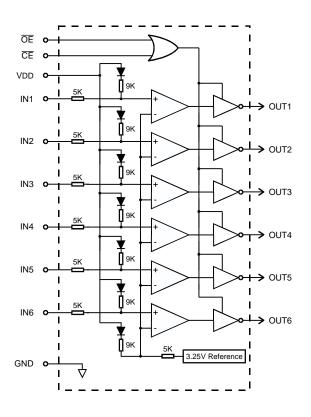
Discrete Input	CE	ŌĒ	Output
Open	0	0	0
Ground	0	0	1
X	1	Х	High Z
X	Х	1	High Z

PIN CONFIGURATION



16-Pin Plastic SOIC package (Narrow Body)

BLOCK DIAGRAM



PIN DESCRIPTIONS

PIN	SYMBOL	FUNCTION	DESCRIPTION
1	IN1	Discrete Input	Open / Ground sensing input, channel 1
2	IN2	Discrete Input	Open / Ground sensing input, channel 2
3	IN3	Discrete Input	Open / Ground sensing input, channel 3
4	IN4	Discrete Input	Open / Ground sensing input, channel 4
5	IN5	Discrete Input	Open / Ground sensing input, channel 5
6	IN6	Discrete Input	Open / Ground sensing input, channel 6
7	ŌĒ	Digital input	Output Enable. OUT1-OUT6 are high-impedance if $\overline{\text{OE}}$ is high
8	CE	Digital input	Chip Enable. OUT1-OUT6 are high-impedance if $\overline{\text{CE}}$ is high
9	VDD	Power	Positive supply voltage 5.0 V
10	OUT6	Tri-state output	Logic output, channel 6
11	OUT5	Tri-state output	Logic output, channel 5
12	OUT4	Tri-state output	Logic output, channel 4
13	OUT3	Tri-state output	Logic output, channel 3
14	OUT2	Tri-state output	Logic output, channel 2
15	OUT1	Tri-state output	Logic output, channel 1
16	GND	Power	Ground

ABSOLUTE MAXIMUM RATINGS

Supply voltage (VDD)	-0.3 V to +7 V			
Logic input voltage range	-0.3 V to +5.5 V			
Discrete input voltage range	-5 V to + 35 V			
Power dissipation at 25°C	350 mW			
Solder temperature	275°C for 10 sec			
Storage temperature	-65°C to +150°C			

RECOMMENDED OPERATING CONDITIONS

ſ	Supply Voltage
	VDD 4.5 V to 5.5 V
Ī	Operating Temperature Range
ı	Industrial Screening40°C to +85°C
ı	Hi-Temp Screening55°C to +125°C

NOTE: Stresses above absolute maximum ratings or outside recommended operating conditions may cause permanent damage to the device. These are stress ratings only. Operation at the limits is not recommended.

ELECTRICAL CHARACTERISTICS

 $VDD = 5.0V \pm 10\%$, GND = 0V, TA = Operating Temperature Range (unless otherwise specified).

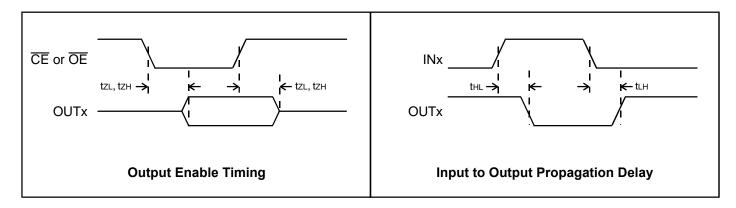
PARAMETER	SYMBOL	CONDITION	MIN	TYP	MAX	UNITS
DISCRETE INPUTS						
Ground state input voltage	Vsg	Input voltage to give high output			3.0	V
Open state input voltage	Vso	Input voltage to give low output	3.5			V
Ground state input resistor	Rıg	Resistor from input to ground to give high output	0		100	Ω
Open state input resistor	Rio	Resistor from input to ground to give low output	100			ΚΩ
Input source current	lio	Current sourced into 100Ω to ground	-100	-330		μА
Reverse leakage current	lir	VIN = 35 V, VDD = 0 V			5.0	mA

ELECTRICAL CHARACTERISTICS (Cont.)

 $VDD = 5.0V \pm 10\%$, GND = 0V, TA = Operating Temperature Range (unless otherwise specified).

PARAMETER	2	SYMBOL	CONDITION	MIN	TYP	MAX	UNITS
LOGIC INPUTS (CE, OE)							
Input Voltage	Input voltage HI	VIH		2.0			V
	Input voltage LO	VIL				0.8	V
Input current	Input sink	Iн	VIH = VDD			1.0	μA
	Input source	Iı∟	VIL = 0 V	-1.0			μΑ
OUTPUTS	_						
Logic output voltage	High	Vон	Iон = -5 mA	2.4			V
	Low	Vol	IoL = 5 mA			0.4	V
Logic output voltage (CMOS)	High	Vон	Iон = -100 uA	VDD - 0.2			V
	Low	Vol	IOL = 100 uA			0.2	V
Tri-state output current		loz	Vout = 0 V or Vdd			±10	μA
SUPPLY CURRENT							
VDD current		ldd	VIN = VDD (all inputs)		5	10	mA
SWITCHING CHARACTERISTIC	S						
Propagation delay	IN to OUT	tLH, tHL				150	ns
Output enable time		tzL, tzH	From CE or OE			25	ns
Output disable time		tLZ, tHZ	From CE or OE			25	ns

TIMING DIAGRAMS



ORDERING INFORMATION

PART NUMBER	PACKAGE DESCRIPTION	TEMPERATURE RANGE	PROCESS FLOW	BURN IN	LEAD FINISH
HI-8420PSI	16 PIN PLASTIC SOIC (NARROW BODY)	-40°C TO +85°C	I	NO	SOLDER
HI-8420PST	16 PIN PLASTIC SOIC (NARROW BODY)	-55°C TO +125°C	Т	NO	SOLDER



PACKAGE DIMENSIONS

inches (millimeters)

